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Application Number	09/918,115
Filing Date	July 30, 2001
First Named Inventor	Graetzel et al.
Group Art Unit	2811
Examiner Name	
Attorney Docket Number	16090-23

OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
SP		VOGEL et al. <u>Sensitization of highly porous, polycrystalline TiO₂ electrodes by quantum sized CdS</u> , Chemical Physics Letters, Nov. 9, 1990, pp. 241-246, Vol.174, No.3,4, Elsevier Science	
SP		O'REGAN et al. <u>A low-cost, high-efficiency solar cell based on dye-sensitized colloidal TiO₂ films</u> , Letters to Nature, Oct. 24, 1991, Vol. 353.	
SP		VOGEL et al. <u>Quantum-Sized PbS, CdS, Ag₂S, Sb₂S₃, and Bi₂S₃ Particles as Sensitizers for Various Nanoporous Wide-Bandgap Semiconductors</u> , J. Phys. Chem., 1994, pp. 3183-2188, Vol. 98.	
SP		Greenham et al. <u>Charge separation and transport in conjugated-polymer/semiconductor-nanocrystal composites ...</u> , Physical Review B., Dec. 15, 1996, pp.628-637, Vol. 54, No. 24.	
SP		Siebentritt et al. <u>CdTe and CdS as Extremely Thin Absorber Materials in an ETA solar cell</u> , 14th European Photovoltaic Solar Energy Conference, June 30, 1997, pp. 1823-1826, Barcelona, SP	
SP		Salafsky et al. <u>Photoinduced charge separation and recombination in a conjugated polymer-semiconductor nanocrystal composite</u> , Chemical Physics Letters, July 3, 1998, pp.297-303, Vol.290, No.4/06	
SP		Rost et al. <u>Transparent P-Type Semiconductors for the eta Solar Cell ...</u> , 2nd Wrld. Conf. and Exh. on Photovoltaic Solar Energy Conversion, July 6-10, 1998, pp.212-215, Vienna, Austria.	
SP		Bach et al. <u>Solid-state dye-sensitized mesoporous TiO₂ solar cells ...</u> , Letters to Nature, Oct. 8, 1998, pp. 583-585, Vol 395, MacMillan Journals Ltd., London.	
SP		Moller et al. <u>A novel disposition technique for compound semiconductors on highly porous substrates: ILGAR</u> , Thin Solid Films, Feb. 21, 2000, pp.113-117, Vol.361/362, Elsevier-Sequoia	
SP		Bach, U., <u>Solid-State Dye-Sensitized Mesoporous TiO₂ Solar Cells</u> , Thesis presented to Ecole Polytechnique Federale de Lausanne, 2000, Lausanne, Switzerland.	

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